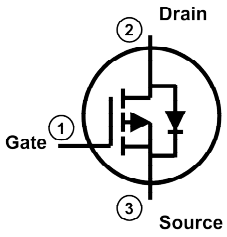
PJD100P04-AU

40V P-Channel Enhancement Mode MOSFET

Voltage	-40 V	Current	-85 A

TO-252AA



Features

- $R_{DS(ON)}$, V_{GS}@-10V, I_D@-20A<6.5mΩ
- $R_{DS(ON)}$, V_{GS}@-4.5V, I_D@-10A<9mΩ
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0105 ounces, 0.297grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-40	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current (Note 4)	T_C=25°C	I_D	-85	A
	T_C=100°C		-53	A
Pulsed Drain Current (Note 1)	T_C=25°C	I_{DM}	-300	A
Power Dissipation	T_C=25°C	P_D	69.4	W
	T_C=100°C		27.8	W
Continuous Drain Current (Note 4)	T_A=25°C	I_D	-14	A
	T_A=70°C		-11	A
Power Dissipation	T_A=25°C	P_D	2.0	W
	T_A=70°C		1.3	W
Single Pulse Avalanche Energy (Note 6)		E_{AS}	245	mJ
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	1.8	°C/W
	Junction to Ambient	$R_{\theta JA}$	62.5	°C/W

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=-250uA	-40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250uA	-1	-1.4	-2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=-10V, I_D=-20A	-	5.1	6.5	mΩ
		V_{GS}=-4.5V, I_D=-10A	-	6.5	9	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-40V, V_{GS}=0V	-	-	-1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V_{DS}=-32V, I_D=-10A, V_{GS}=-10V (Note 2,3)	-	128	-	nC
Gate-Source Charge	Q_{gs}		-	14.4	-	
Gate-Drain Charge	Q_{gd}		-	28.9	-	
Input Capacitance	Ciss	V_{DS}=-25V, V_{GS}=0V, f=1MHZ	-	6324	-	pF
Output Capacitance	Coss		-	548	-	
Reverse Transfer Capacitance	Crss		-	292	-	
Gate resistance	Rg	f=1MHZ	-	3.7	-	Ω
Turn-On Delay Time	$td_{(on)}$	V_{DS}=-32V, I_D=-1A, V_{GS}=-10V, R_G=6Ω (Note 2,3)	-	12	-	ns
Turn-On Rise Time	t_r		-	18.6	-	
Turn-Off Delay Time	$td_{(off)}$		-	241	-	
Turn-Off Fall Time	t_f		-	91	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-85	A
Diode Forward Voltage	V_{SD}	I_S=-1A, V_{GS}=0V	-	-0.66	-1	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
4. The maximum current rating is package limited.
5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch^2 with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I_{AS}=-70A, V_{DD}=-25V, V_{GS}=-10V, Starting T_J=25°C.
7. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

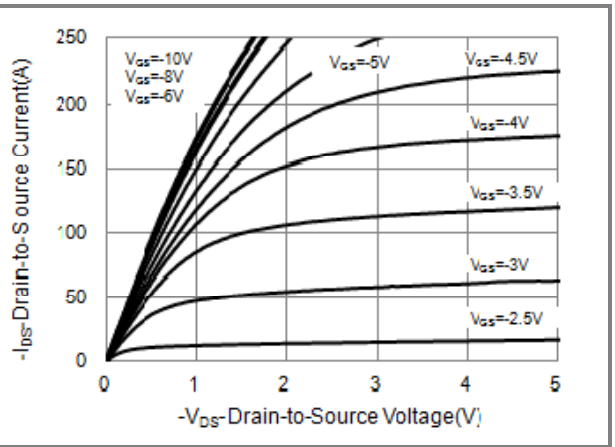

Fig.1 Output Characteristics

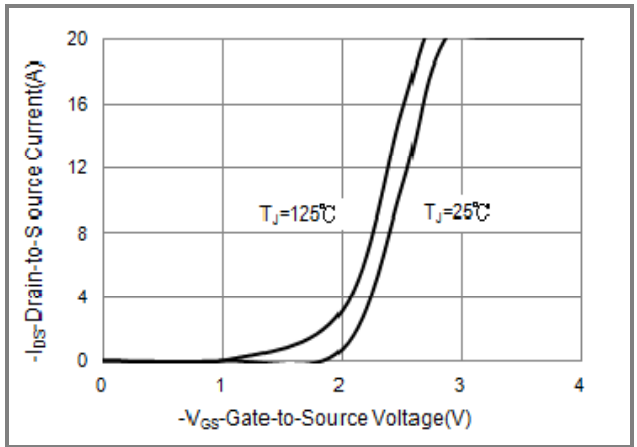

Fig.2 Transfer Characteristics

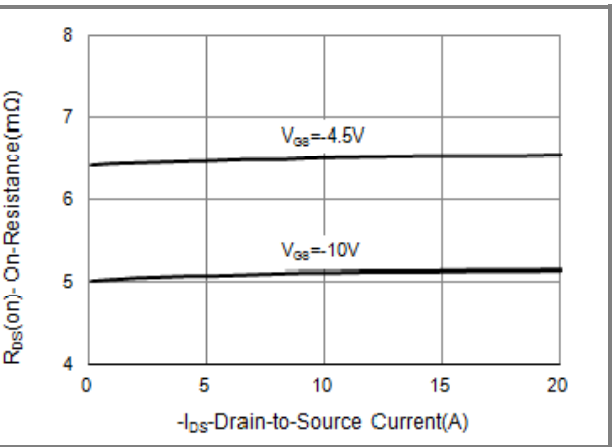

Fig.3 On-Resistance vs. Drain Current

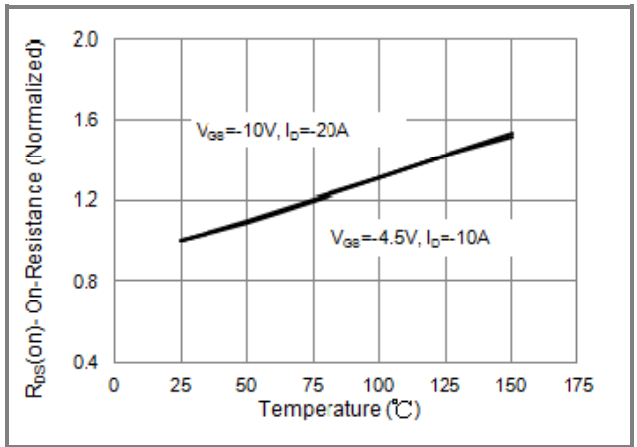

Fig.4 On-Resistance vs. Junction temperature

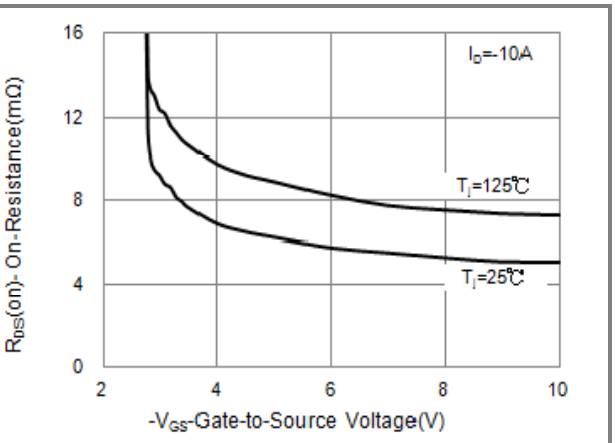

Fig.5 On-Resistance Variation with V_{GS}

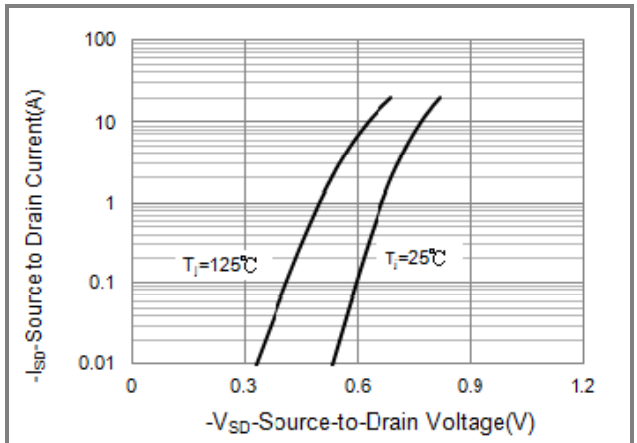

Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

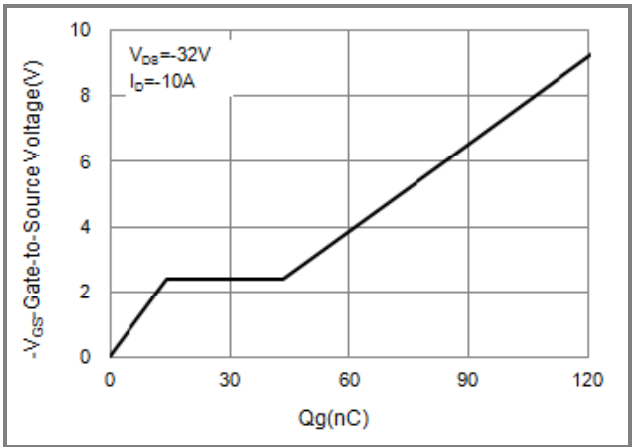

Fig.7 Gate-Charge Characteristics

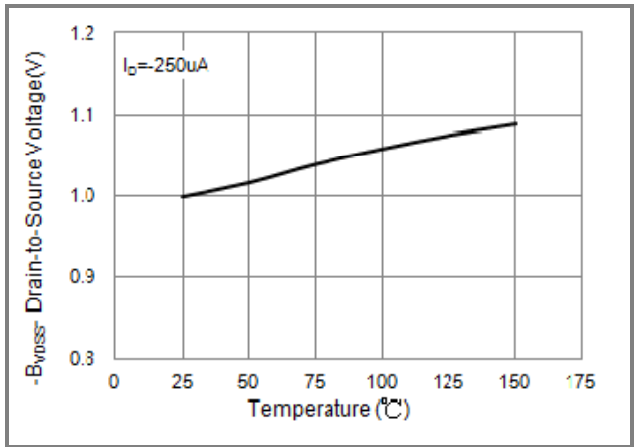

Fig.8 Breakdown Voltage Variation vs. Temperature

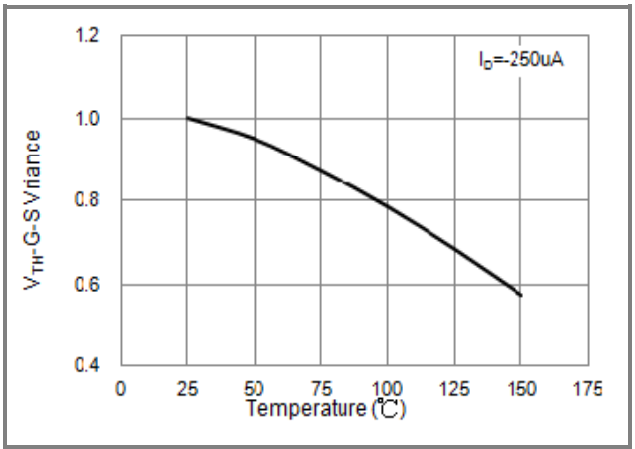

Fig.9 Threshold Voltage Variation with Temperature

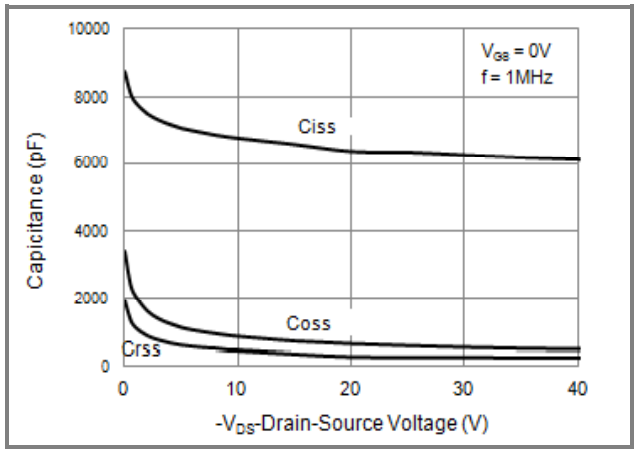

Fig.10 Capacitance vs. Drain-Source Voltage

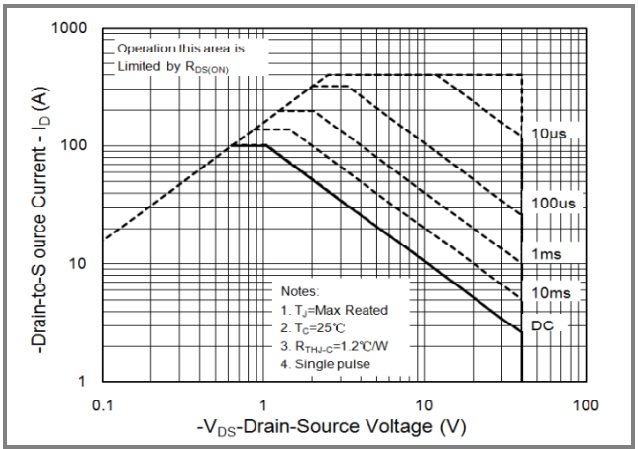

Fig.11 Maximum Safe Operating Area

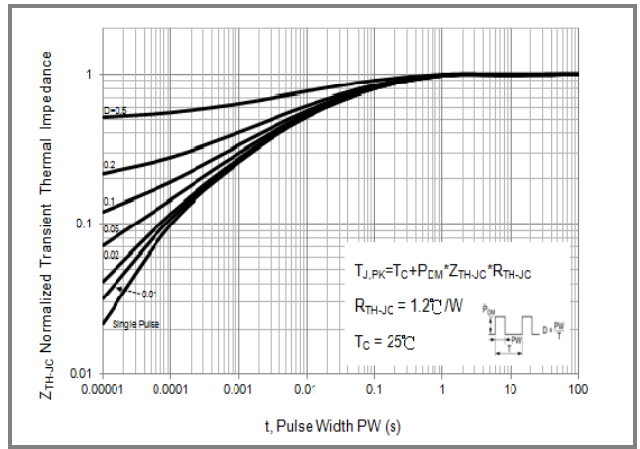

Fig.12 Normalized Transient Thermal Impedance

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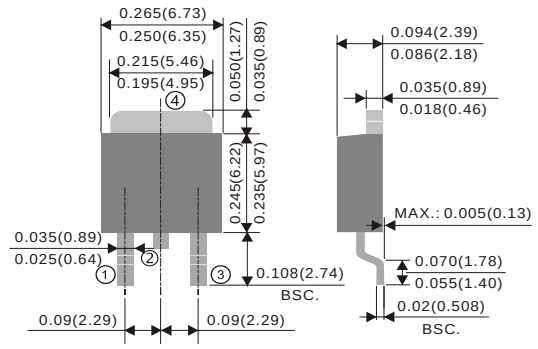
Part No. Packing Code Version

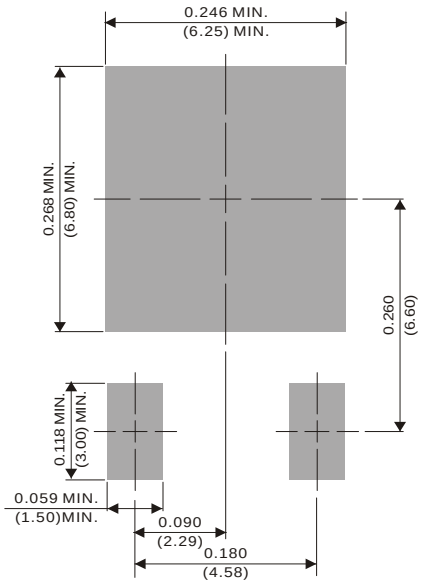
Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJD100P04-AU_L2_000A1	TO-252AA	3,000pcs / 13” reel	D100P04	Halogen free

Packaging Information & Mounting Pad Layout

TO-252AA Dimension — Unit: inch(mm)



TO-252AA Pad Layout — Unit: inch(mm)



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